

Ultra low capacitance ESD protection diode in SOT23 package

Rev. 02 — 20 August 2009 Product data sheet

### **Product profile**

#### 1.1 General description

Ultra low capacitance ElectroStatic Discharge (ESD) protection diode in a SOT23 (TO-236AB) small SMD plastic package designed to protect one high-speed data line from the damage caused by ESD and other transients.

#### 1.2 Features

- Unidirectional ESD protection of one line ESD protection > 23 kV
- Ultra low diode capacitance: C<sub>d</sub> = 0.6 pF IEC 61000-4-2; level 4 (ESD)
- Max. peak pulse power: P<sub>PP</sub> up to 200 W IEC 61000-4-5; (surge)
- Low clamping voltage

#### 1.3 Applications

- 10/100/1000 Ethernet
- FireWire
- Communication systems
- Local Area Network (LAN) equipment
- Computers and peripherals
- High-speed data lines

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{RWM}$	reverse stand-off voltage					
	PESD3V3U1UT		-	-	3.3	V
	PESD5V0U1UT		-	-	5.0	V
	PESD12VU1UT		-	-	12	V
	PESD15VU1UT		-	-	15	V
	PESD24VU1UT		-	-	24	V
$C_d$	diode capacitance	$f = 1 \text{ MHz}; V_R = 0 \text{ V}$	-	0.6	1.5	pF

<sup>[1]</sup> Measured from pin 1 to 2



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### 2. Pinning information

Table 2. Pinning

Idbic 2.	i iiiiiiig		
Pin	Description	Simplified outline	Symbol
1	cathode ESD protection diode		
2	cathode compensation diode	3	3
3	common anode	1 2	1 2 006aaa441

## 3. Ordering information

Table 3. Ordering information

Type number	Package	Package				
	Name	Description	Version			
PESD3V3U1UT	-	plastic surface mounted package; 3 leads	SOT23			
PESD5V0U1UT						
PESD12VU1UT						
PESD15VU1UT						
PESD24VU1UT						

### 4. Marking

Table 4. Marking codes

Type number	Marking code <sup>[1]</sup>
PESD3V3U1UT	*AP
PESD5V0U1UT	*AQ
PESD12VU1UT	*AR
PESD15VU1UT	*AS
PESD24VU1UT	*AT

<sup>[1] \* = -:</sup> made in Hong Kong

<sup>\* =</sup> p: made in Hong Kong

<sup>\* =</sup> t: made in Malaysia

<sup>\* =</sup> W: made in China

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
P <sub>PP</sub>	peak pulse power	8/20 μs	<u>[1]</u>		
	PESD3V3U1UT		-	80	W
	PESD5V0U1UT		-	80	W
	PESD12VU1UT		-	200	W
	PESD15VU1UT		-	200	W
	PESD24VU1UT		-	200	W
I <sub>PP</sub>	peak pulse current	8/20 μs	<u>[1]</u>		
	PESD3V3U1UT		-	5	Α
	PESD5V0U1UT		-	5	Α
	PESD12VU1UT		-	5	Α
	PESD15VU1UT		-	5	Α
	PESD24VU1UT		-	3	Α
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

Table 6. ESD maximum ratings

	•					
Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>ESD</sub>	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	[1][2]			
	PESD3V3U1UT			-	30	kV
	PESD5V0U1UT			-	30	kV
	PESD12VU1UT			-	30	kV
	PESD15VU1UT			-	30	kV
	PESD24VU1UT			-	23	kV
	PESDxU1UT	HBM MIL-STD-883		-	10	kV

<sup>[1]</sup> Device stressed with ten non-repetitive ESD pulses.

Table 7. ESD standards compliance

Standard	Conditions
IEC 61000-4-2; level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
HBM MIL-STD-883; class 3	> 4 kV

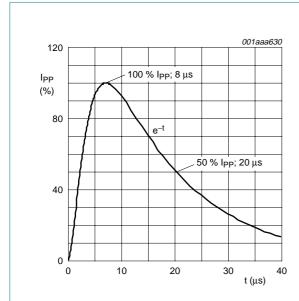


Fig 1. 8/20 µs pulse waveform according to IEC 61000-4-5

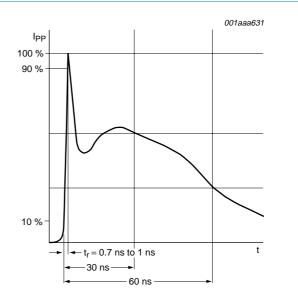


Fig 2. ESD pulse waveform according to IEC 61000-4-2

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<sup>[2]</sup> Measured from pin 1 to 2

### 6. Characteristics

Table 8. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified

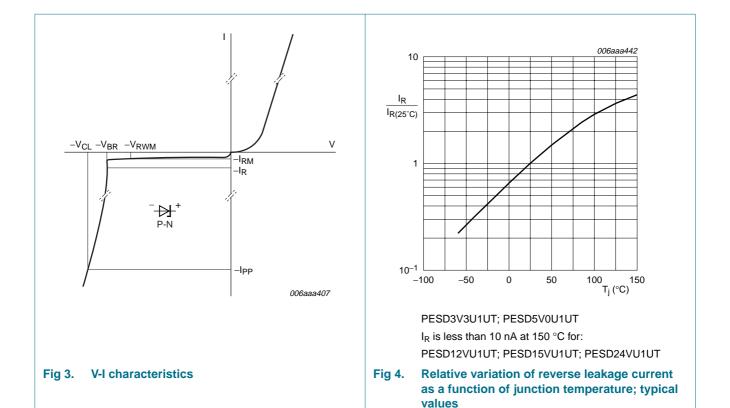
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
/ <sub>RWM</sub>	reverse stand-off voltage					
	PESD3V3U1UT		-	-	3.3	V
	PESD5V0U1UT		-	-	5.0	V
	PESD12VU1UT		-	-	12	V
	PESD15VU1UT		-	-	15	V
	PESD24VU1UT		-	-	24	V
I <sub>RM</sub>	reverse leakage current					
	PESD3V3U1UT	$V_{RWM} = 3.3 V$	-	0.25	2	μΑ
	PESD5V0U1UT	$V_{RWM} = 5.0 V$	-	0.03	1	μΑ
	PESD12VU1UT	$V_{RWM} = 12 V$	-	< 1	50	nA
	PESD15VU1UT	$V_{RWM} = 15 V$	-	< 1	50	nA
	PESD24VU1UT	$V_{RWM} = 24 V$	-	< 1	50	nA
$V_{BR}$	breakdown voltage	$I_R = 5 \text{ mA}$	[2]			
	PESD3V3U1UT		5.8	6.4	6.9	V
	PESD5V0U1UT		7.0	7.6	8.2	V
	PESD12VU1UT		14.2	15.0	16.7	V
	PESD15VU1UT		17.1	18.9	20.3	V
	PESD24VU1UT		25.4	27.8	30.3	V
C <sub>d</sub>	diode capacitance	$f = 1 MHz; V_R = 0 V$	[2] -	0.6	1.5	pF
V <sub>CL</sub>	clamping voltage		[1][2]			
	PESD3V3U1UT	I <sub>PP</sub> = 1 A	-	-	9	V
		I <sub>PP</sub> = 5 A	-	-	20	V
	PESD5V0U1UT	I <sub>PP</sub> = 1 A	-	-	12	V
		I <sub>PP</sub> = 5 A	-	-	21	V
	PESD12VU1UT	I <sub>PP</sub> = 1 A	-	-	23	V
		$I_{PP} = 5 A$	-	-	39	V
	PESD15VU1UT	I <sub>PP</sub> = 1 A	-	-	28	V
		I <sub>PP</sub> = 5 A	-	-	53	V
	PESD24VU1UT	I <sub>PP</sub> = 1 A	-	-	40	V
		I <sub>PP</sub> = 3 A	-	-	76	V
dif	differential resistance	I <sub>R</sub> = 1 mA				
	PESD3V3U1UT		-	-	400	Ω
	PESD5V0U1UT		-	-	80	Ω
	PESD12VU1UT		-	-	200	Ω
	PESD15VU1UT		-	-	225	Ω
	PESD24VU1UT		-	-	300	Ω

<sup>[1]</sup> Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

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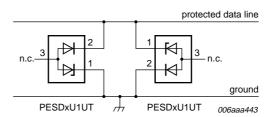
<sup>[2]</sup> Measured from pin 1 to 2

### Ultra low capacitance ESD protection diode in SOT23 package



### 7. Application information

The PESDxU1UT series is designed for protection of high-speed datalines from damage caused by ESD and surge pulses. PESDxU1UT devices combine an ESD protection diode and an ultra low capacitance compensation diode to ensure an effective device capacitance as low as 0.6 pF. The PESDxU1UT series provides a surge capability of up to 200 W per line for an 8/20 µs waveform.



Two PESDxU1UT devices in anti-parallel configuration provide ESD protection in a common-mode application.

The two PESDxU1UT devices should be connected as follows:

#### protected data line is connected to

device 1 / pin 2

device 2 / pin 1

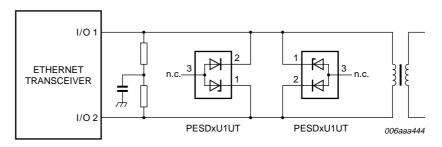
#### Ground is connected to

device 1 / pin 1

device 2 / pin 2

pin 3 is not connected for both devices

Fig 5. Bidirectional ESD protection of one line, common mode



Two PESDxU1UT devices in anti-parallel configuration provide ESD protection in a differential-mode configuration as e.g. for Ethernet applications.

The two PESDxU1UT should be connected as follows:

#### I/O line 1 is connected to

device 1 / pin 2

device 2 / pin 1

#### I/O line 2 is connected to

device 1 / pin 1

device 2 / pin 2

pin 3 is not connected for both devices

#### Fig 6. Differential mode Ethernet protection

#### Ultra low capacitance ESD protection diode in SOT23 package

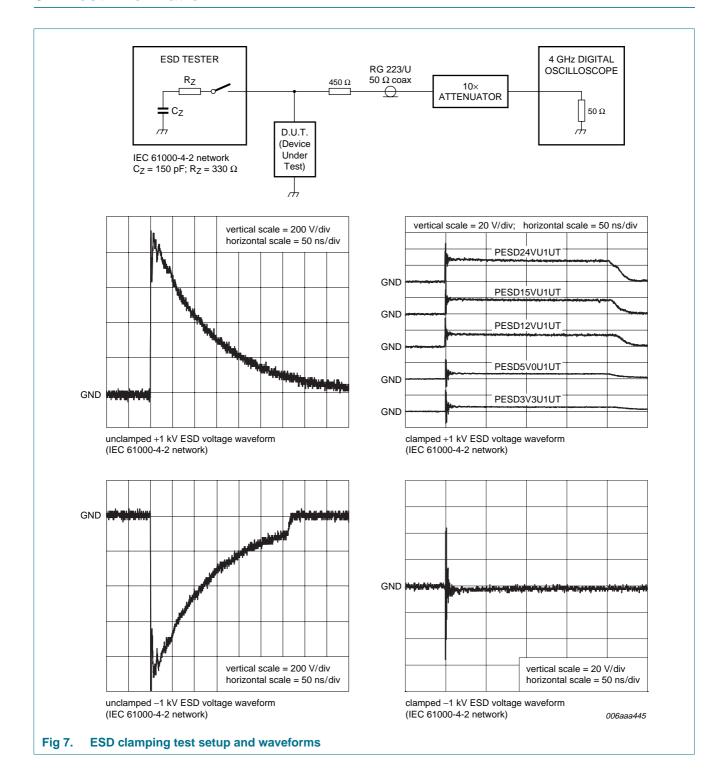
#### Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

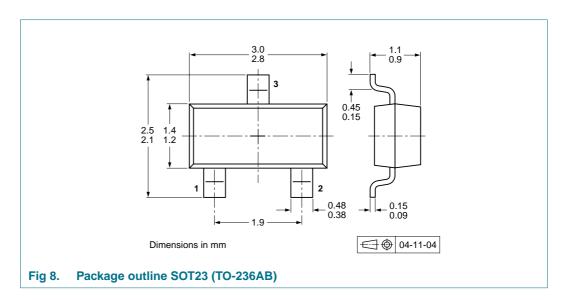
- 1. Place the PESDxU1UT as close to the input terminal or connector as possible.
- 2. The path length between the PESDxU1UT and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all printed-circuit board conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Ground planes should be used whenever possible. For multilayer printed-circuit boards, use ground vias.

Ultra low capacitance ESD protection diode in SOT23 package

### 8. Test information



### 9. Package outline



## 10. Packing information

Table 9. Packing methods

The -xxx numbers are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing	Packing quantity		
			3000	10000		
PESD3V3U1UT	SOT23	9T23 4 mm pitch, 8 mm tape and reel	-215	-235		
PESD5V0U1UT						
PESD12VU1UT						
PESD15VU1UT						
PESD24VU1UT						

<sup>[1]</sup> For further information and the availability of packing methods, see Section 13.

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## 11. Revision history

#### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PESDXU1UT_SER_2	20090820	Product data sheet	-	PESDXU1UT_SER_1
Modifications:		eet was changed to reflect v legal definitions and disc		
PESDXU1UT_SER_1	20050511	Product data sheet	-	-

#### Ultra low capacitance ESD protection diode in SOT23 package

### 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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MPC565MVR56 MPC574XG-176DS MPC860PCVR66D4 BT137-600E BT139X-600.127 BUK7628-100A118 BUK765R0-100E.118
BZT52H-B9V1.115 BZV85-C3V9.113 BZX79-C47.113 P5020NSE7VNB S12ZVML12EVBLIN SCC2692AC1N40 LPC1785FBD208K
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